SEMICONDUCTOR

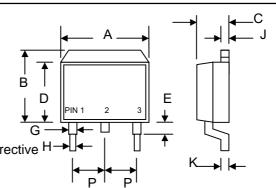
8.0A D²PAK SURFACE MOUNT SUPER FAST RECTIFIER

Data Sheet 4825, Rev. -

Green Products

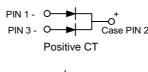
Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Profile Package
- High Surge Current Capability
- Low Power Loss, High Efficiency
- Super-Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- Green Products in Compliance with the RoHS Directive H



Mechanical Data

- Case: Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 1.7 grams (approx.)
- Mounting Position: Any
- Marking: Type Number
- Standard Packaging: 24mm Tape (EIA-481)



PIN 1 +	о <u>—</u>	 					
PIN 3 +	0—	 	Case PIN 2				
Negative CT							
	Suffi	ix with	"N"				

D ² PAK/TO-263								
Dim	Min	Max	Min	Max				
Α	9.80	10.40	0.386	0.409				
В	9.60	10.60	0.378	0.417				
C	4.40	4.80	0.173	0.189				
D	8.50	9.10	0.335	0.358				
Е	_	0.70	_	0.028				
G	1.00	1.40	0.039	0.055				
H	_	0.90	_	0.035				
ſ	1.20	1.40	0.047	0.055				
K	0.30	0.70	0.012	0.028				
Р	2.35	2.75	0.093	0.108				
	In r	nm	In inch					

Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	ER 800D-G	ER 801D-G	ER 801AD-G	ER 802D-G	ER 803D-G	ER 804D-G	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	50	100	150	200	300	400	V
RMS Reverse Voltage	VR(RMS)	35	70	105	140	210	280	V
Average Rectified Output Current @T _C = 100°C	lo	8.0					Α	
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	IFSМ	125				Α		
Forward Voltage @I _F = 8.0A	VFM	0.95 1.3					٧	
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	lгм	10 300			μA			
Reverse Recovery Time (Note 1)	trr	35 50			0	nS		
Typical Junction Capacitance (Note 2)	Cj	70 50			0	pF		
Operating and Storage Temperature Range	Тj, Tsтg	-50 to +150				°C		

Note: 1. Measured with $I_F = 0.5A$, $I_R = 1.0A$, $I_{rr} = 0.25A$.

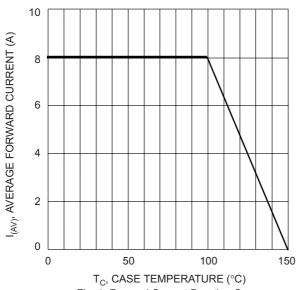
2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

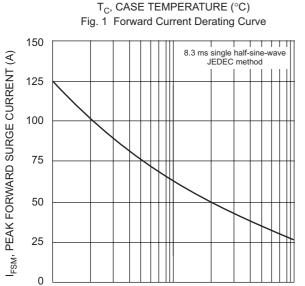
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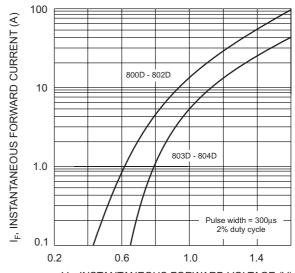
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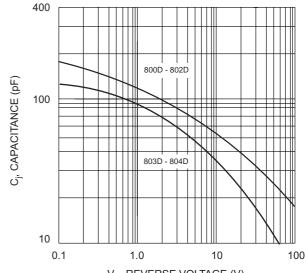


NUMBER OF CYCLES AT 60Hz Fig. 3 Max Non-Repetitive Surge Current

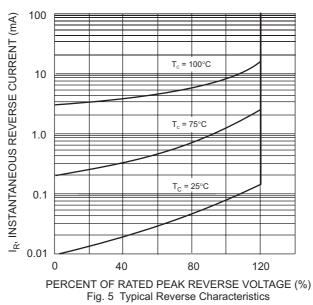
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V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics



V_R, REVERSE VOLTAGE (V) Fig. 4 Typical Junction Capacitance



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SENSITRON SEMICONDUCTOR

ER800D-G-ER804D-G

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